NSN 5961-01-369-4899



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-369-4899 **Inclosure Material:** Metal **Overall Length:** 2.365 inches **Overall Diameter:** Between 1.042 inches and 1.062 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-114 **Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 collector to base voltage/static/emitter open and 400.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 60.00 amperes all primaries **Power Rating Per Characteristic:** 350.0 watts any acceptable preset **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 wire loop Shelf Life:

Demilitarization: No

Unit Of Measure:

N/a

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